## Dual 1-of-4 Decoder/ Demultiplexer

The LSTTL/MSI SN74LS139 is a high speed Dual 1-of-4 Decoder/Demultiplexer. The device has two independent decoders, each accepting two inputs and providing four mutually exclusive active LOW Outputs. Each decoder has an active LOW Enable input which can be used as a data input for a 4-output demultiplexer. Each half of the LS139 can be used as a function generator providing all four minterms of two variables. The LS139 is fabricated with the Schottky barrier diode process for high speed and is completely compatible with all ON Semiconductor TTL families.

- Schottky Process for High Speed
- Multifunction Capability
- Two Completely Independent 1-of-4 Decoders
- Active Low Mutually Exclusive Outputs
- Input Clamp Diodes Limit High Speed Termination Effects
- ESD > 3500 Volts

#### **GUARANTEED OPERATING RANGES**

Symbol	Parameter	Min	Тур	Max	Unit
VCC	Supply Voltage	4.75	5.0	5.25	V
T <sub>A</sub>	Operating Ambient Temperature Range	0	25	70	°C
ІОН	Output Current – High			-0.4	mA
lOL	Output Current – Low			8.0	mA



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# LOW POWER SCHOTTKY



PLASTIC N SUFFIX CASE 648



SOIC D SUFFIX CASE 751B



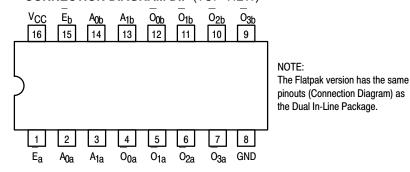
SOEIAJ M SUFFIX CASE 966

#### **ORDERING INFORMATION**

Device	Package	Shipping
SN74LS139N	16 Pin DIP	2000 Units/Box
SN74LS139D	SOIC-16	38 Units/Rail
SN74LS139DR2	SOIC-16	2500/Tape & Reel
SN74LS139M	SOEIAJ-16	See Note 1
SN74LS139MEL	SOEIAJ-16	See Note 1

 For ordering information on the EIAJ version of the SOIC package, please contact your local ON Semiconductor representative.

#### **CONNECTION DIAGRAM DIP (TOP VIEW)**



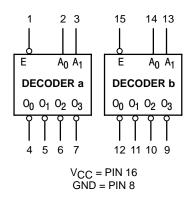
# LOADING (Note a)

PIN NAMES		пібп	LOW
A <sub>0</sub> , A <sub>1</sub>	Address Inputs	0.5 U.L.	0.25 U.L.
<u>E</u> _	Enable (Active LOW) Input	0.5 U.L.	0.25 U.L.
00 - 03	Active LOW Outputs	10 U.L.	5 U.L.

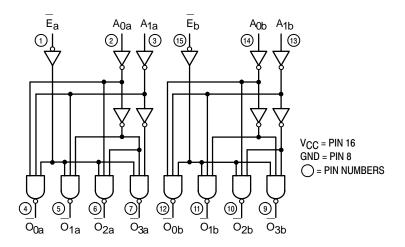
#### NOTES:

a) 1 TTL Unit Load (U.L.) = 40  $\mu$ A HIGH/1.6 mA LOW.

#### **LOGIC SYMBOL**



#### **LOGIC DIAGRAM**



#### **FUNCTIONAL DESCRIPTION**

The LS139 is a high speed dual 1-of-4 decoder/demultiplexer fabricated with the Schottky barrier diode process. The device has two independent decoders, each of which accept two binary weighted inputs (A<sub>0</sub>, A<sub>1</sub>) and provide four mutually exclusive active LOW outputs (O<sub>0</sub>-O<sub>3</sub>). Each decoder has an active LOW Enable (E). When E is HIGH all outputs are forced HIGH. The enable

can be used as the data input for a 4-output demultiplexer application.

Each half of the LS139 generates all four minterms of two variables. These four minterms are useful in some applications, replacing multiple gate functions as shown in Fig. a, and thereby reducing the number of packages required in a logic network.

**TRUTH TABLE** 

INPUTS				OUT	PUTS	
E	Α0	A <sub>1</sub>	00	0 <sub>1</sub>	02	03
Н	Х	Х	Н	Н	Н	Н
L	L	L	L	Н	Н	Н
L	Н	L	Н	L	Н	Н
L	L	Н	Н	Н	L	Н
L	Н	Н	Н	Н	Н	L

H = HIGH Voltage Level L = LOW Voltage Level

X = Don't Care

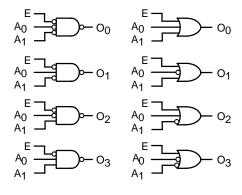


Figure a

#### DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Tes	t Conditions
VIH	Input HIGH Voltage	2.0			V	Guaranteed Input HIGH Voltage for All Inputs	
VIL	Input LOW Voltage			0.8	V	Guaranteed Input LOW Voltage for All Inputs	
VIK	Input Clamp Diode Voltage		-0.65	-1.5	V	V <sub>CC</sub> = MIN, I <sub>IN</sub> = -18 mA	
Vон	Output HIGH Voltage	2.7	3.5		V	$V_{CC}$ = MIN, $I_{OH}$ = MAX, $V_{IN}$ = $V_{IH}$ or $V_{IL}$ per Truth Table	
V	Output I OW/Vallage		0.25	0.4	V	I <sub>OL</sub> = 4.0 mA	V <sub>CC</sub> = V <sub>CC</sub> MIN,
VOL	Output LOW Voltage		0.35	0.5	V	I <sub>OL</sub> = 8.0 mA	V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub> per Truth Table
1	Innut I II CI I Current			20	μΑ	V <sub>CC</sub> = MAX, V <sub>IN</sub>	= 2.7 V
lіН	Input HIGH Current			0.1	mA	V <sub>CC</sub> = MAX, V <sub>IN</sub> = 7.0 V	
IIL	Input LOW Current			-0.4	mA	V <sub>CC</sub> = MAX, V <sub>IN</sub> = 0.4 V	
los	Short Circuit Current (Note 2)	-20		-100	mA	V <sub>CC</sub> = MAX	
Icc	Power Supply Current			11	mA	V <sub>CC</sub> = MAX	

<sup>2.</sup> Not more than one output should be shorted at a time, nor for more than 1 second.

#### AC CHARACTERISTICS ( $T_A = 25^{\circ}C$ )

		Levels of		Limits			
Symbol	Parameter	Delay	Min	Тур	Max	Unit	Test Conditions
tPLH tPHL	Propagation Delay Address to Output	2 2		13 22	20 33	ns	
<sup>t</sup> PLH <sup>t</sup> PHL	Propagation Delay Address to Output	3 3		18 25	29 38	ns	$V_{CC} = 5.0 \text{ V}$ $C_L = 15 \text{ pF}$
<sup>t</sup> PLH <sup>t</sup> PHL	Propagation Delay Enable to Output	2 2		16 21	24 32	ns	

#### **AC WAVEFORMS**

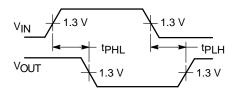


Figure 1.

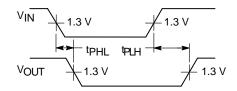
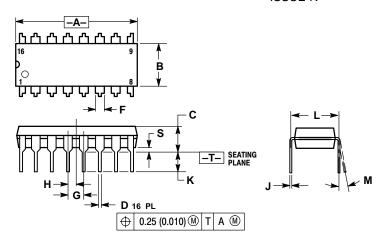


Figure 2.

#### **PACKAGE DIMENSIONS**

#### **N SUFFIX** PLASTIC PACKAGE CASE 648-08 ISSUE R

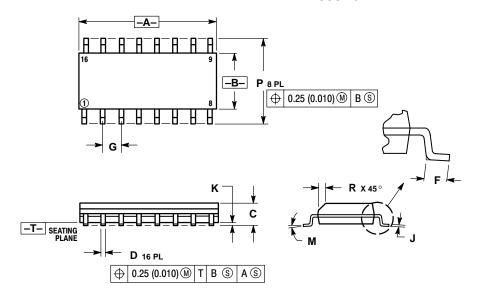


- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
  4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
  5. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIN	ETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.740	0.770	18.80	19.55	
В	0.250	0.270	6.35	6.85	
С	0.145	0.175	3.69	4.44	
D	0.015	0.021	0.39	0.53	
F	0.040	0.70	1.02	1.77	
G	0.100	BSC	2.54 BSC		
Н	0.050	BSC	1.27 BSC		
J	0.008	0.015	0.21	0.38	
K	0.110	0.130	2.80	3.30	
L	0.295	0.305	7.50	7.74	
M	0°	10°	0°	10 °	
S	0.020	0.040	0.51	1.01	

#### **PACKAGE DIMENSIONS**

#### **D SUFFIX** PLASTIC SOIC PACKAGE CASE 751B-05 **ISSUE J**



#### NOTES:

- NOTES:

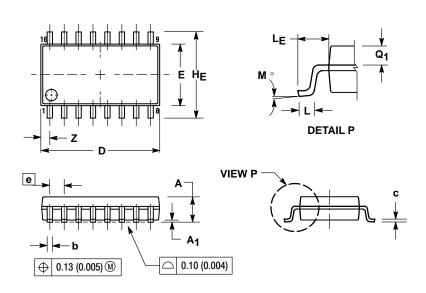
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
  3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
  4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
  5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	9.80	10.00	0.386	0.393	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.054	0.068	
D	0.35	0.49	0.014	0.019	
F	0.40	1.25	0.016	0.049	
G	1.27	BSC	0.050 BSC		
J	0.19	0.25	0.008	0.009	
K	0.10	0.25	0.004	0.009	
M	0°	7°	0°	7°	
P	5.80	6.20	0.229	0.244	
R	0.25	0.50	0.010	0.019	

#### **PACKAGE DIMENSIONS**

#### **M SUFFIX**

SOEIAJ PACKAGE CASE 966-01 **ISSUE O** 



#### NOTES:

- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: MILLIMETER.

  3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE
- PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006)
  PER SIDE.

  4. TERMINAL NUMBERS ARE SHOWN FOR
  REFERENCE ONLY.

  5. THE LEAD WIDTH DIMENSION (b) DOES NOT
  INCLUDE DAMBAR PROTRUSION. ALLOWABLE
  DAMBAR PROTRUSION SHALL BE 0.08 (0.003)
  TOTAL IN EXCESS OF THE LEAD WIDTH
  DIMENSION AT MAXIMUM MATERIAL CONDITION.
  DAMBAR CANNOT BE LOCATED ON THE LOWER
  RADIUS OR THE FOOT. MINIMUM SPACE
  BETWEEN PROTRUSIONS AND ADJACENT LEAD
  TO BE 0.46 (0.018).

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α		2.05		0.081
Α <sub>1</sub>	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
С	0.18	0.27	0.007	0.011
D	9.90	10.50	0.390	0.413
E	5.10	5.45	0.201	0.215
е	1.27	BSC	0.050 BSC	
HE	7.40	8.20	0.291	0.323
L	0.50	0.85	0.020	0.033
LE	1.10	1.50	0.043	0.059
M	0 °	10°	0 °	10 °
Q <sub>1</sub>	0.70	0.90	0.028	0.035
Z		0.78		0.031

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